



SLPS269A - JUNE 2010-REVISED JULY 2011

P-Channel NexFET[™] Power MOSFET

Check for Samples: CSD25201W15

FEATURES

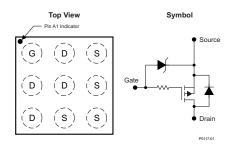
- Low Resistance
- Small Footprint 1.5-mm × 1.5-mm
- Gate ESD Protection –3kV
- Pb Free
- RoHS Compliant
- Halogen Free
- Gate-Source Voltage Clamp

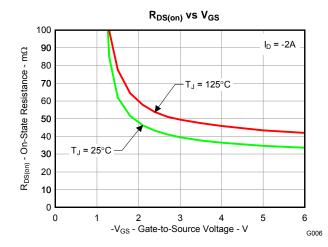
APPLICATIONS

- Battery Management
- Battery Protection

DESCRIPTION

The device has been designed to deliver the lowest on resistance and gate charge in the smallest outline possible with excellent thermal characteristics in an ultra low profile. Low on resistance coupled with the small footprint and low profile make the device ideal for battery operated space constrained applications.





PRODUCT SUMMARY

V _{DS}	Drain to Drain Voltage	-20		V
Qg	Gate Charge Total (-4.5V)	4.3		nC
Q _{gd}	Gate Charge Gate to Drain	0.7		nC
	Drain to Source On Resistance	$V_{GS} = -1.8V$	52	mΩ
R _{DS(on)}		$V_{GS} = -2.5V$	42	mΩ
		V _{GS} = -4.5V 33		mΩ
V _{GS(th)}	Threshold Voltage	-0.7		V

ORDERING INFORMATION

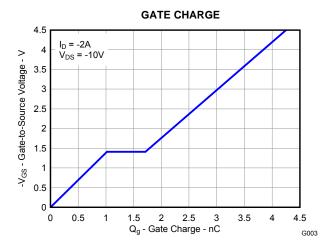
Device	Package	Media	Qty	Ship
CSD25201W15	1.5-mm × 1.5-mm Wafer Level Package	7-Inch Reel	3000	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

$T_A = 28$	5°C unless otherwise stated	VALUE	UNIT
V _{DS}	Drain to Source Voltage	-20	V
V_{GS}	Gate to Source Voltage	-6	V
	Continuous Drain Current ⁽¹⁾⁽²⁾	4	А
ID	Pulsed Drain Current ⁽¹⁾⁽²⁾	4	А
	Continuous Gate Current ⁽¹⁾⁽²⁾	0.5	А
I _G	Pulsed Gate Current ⁽¹⁾⁽²⁾	7	А
PD	Power Dissipation ⁽¹⁾	1.5	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C

(1) Based on Min Cu footprint

(2) Ball limited



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

 $\overline{\Lambda}\overline{\Lambda}$

SLPS269A-JUNE 2010-REVISED JULY 2011

www.ti.com



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

$(T_A = 25^{\circ}C \text{ unless otherwise stated})$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Cl	haracteristics	•	·		,	
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_{DS} = -250\mu A$	-20			V
BV _{GSS}	Gate to Source Voltage	$V_{DS} = 0V, I_G = -250\mu A$	-6.1		-7.2	V
I _{DDS}	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = -16V$			-1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = -6V$			-100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = -250 \mu A$	-0.4	-0.7	-1.1	V
		$V_{GS} = -1.8V, I_{DS} = -2A$		52	70	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = -2.5V, I_{DS} = -2A$		42	50	mΩ
		$V_{GS} = -4.5V, I_{DS} = -2A$		33	40	mΩ
g _{fs}	Transconductance	$V_{DS} = -10V, I_{DS} = -2A$		12		S
Dynamic	c Characteristics				·	
C _{ISS}	Input Capacitance			490	640	pF
C _{OSS}	Output Capacitance	$V_{GS} = 0V, V_{DS} = -10V,$ f = 1MHz		215	280	pF
C _{RSS}	Reverse Transfer Capacitance			70	91	pF
R _G	Series Gate Resistance ⁽¹⁾			26	35	Ω
Qg	Gate Charge Total (-4.5V)			4.3	5.6	nC
Q _{gd}	Gate Charge - Gate to Drain	$V_{DS} = -10V,$ $I_{O} = -2A$		0.7		nC
Q _{gs}	Gate Charge - Gate to Source			1		nC
Q _{g(th)}	Gate Charge at Vth			0.3		nC
Q _{OSS}	Output Charge	$V_{DS} = -9.5V, V_{GS} = 0V$		3.1		nC
t _{d(on)}	Turn On Delay Time ⁽²⁾			9.5		ns
t _r	Rise Time ⁽²⁾	$V_{DS} = -10V, V_{GS} = -4.5V,$		11		ns
t _{d(off)}	Turn Off Delay Time ⁽²⁾	$I_{DS} = -2A, R_G = 2\Omega$		51		ns
t _f	Fall Time ⁽²⁾			38		ns
Diode Cl	haracteristics					
V _{SD}	Diode Forward Voltage	$I_{DS} = -2A, V_{GS} = 0V$		0.7	1	V
Q _{rr}	Reverse Recovery Charge	$V_{DD} = -9.5V, I_F = -2A,$		5.7		nC
t _{rr}	Reverse Recovery Time	di/dt = 200A/µs		10		ns

Includes gate clamp resistor (1)

External R_G is in addition to the internal gate clamp resistor (2)

THERMAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

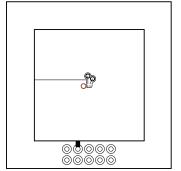
PARAMETER		MIN	TYP	MAX	UNIT
D	Junction to Ambient Thermal Resistance ⁽¹⁾			283	°C/W
R _{θJA}	Junction to Ambient Thermal Resistance ⁽²⁾			185	°C/W

(1)

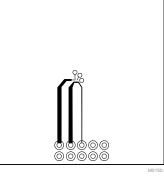
Device mounted on FR4 material with minimum Cu mounting area. Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu. (2)



SLPS269A - JUNE 2010-REVISED JULY 2011



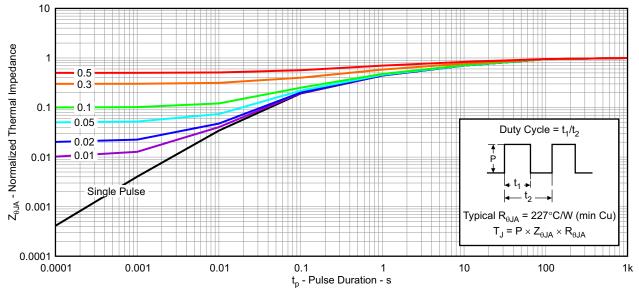
Max $R_{\theta JA} = 185^{\circ}C/W$ when mounted on 1 inch² (6.45 cm²) of 2-oz. (0.071-mm thick) Cu.



Max $R_{\theta JA} = 283^{\circ}C/W$ when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

TYPICAL MOSFET CHARACTERISTICS

 $T_A = 25^{\circ}C$, unless stated otherwise.



G012

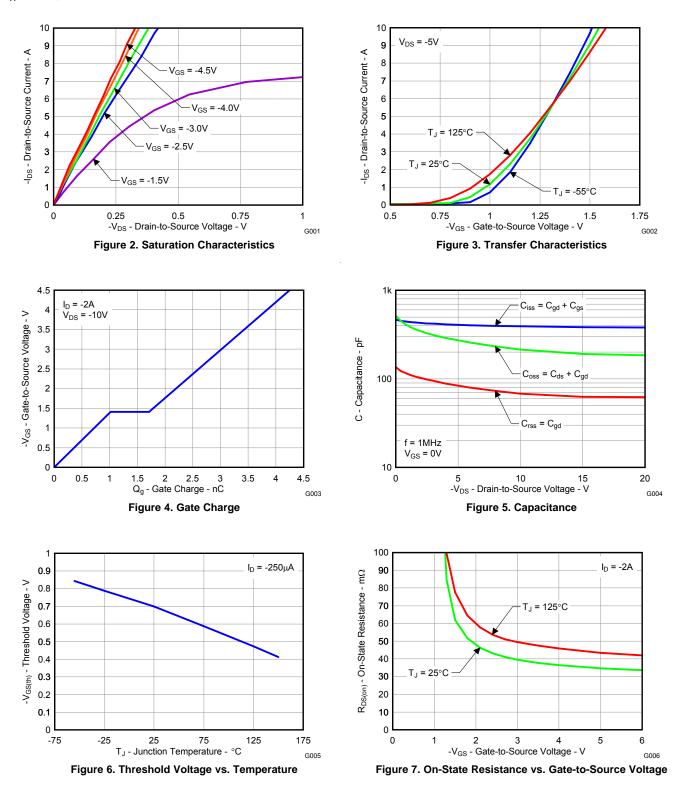
Figure 1. Transient Thermal Impedance

ISTRUMENTS

ÈXAS

TYPICAL MOSFET CHARACTERISTICS (continued)

 $T_A = 25^{\circ}C$, unless stated otherwise.





CSD25201W15

SLPS269A -JUNE 2010-REVISED JULY 2011

www.ti.com

TYPICAL MOSFET CHARACTERISTICS (continued)

 $T_A = 25^{\circ}C$, unless stated otherwise.

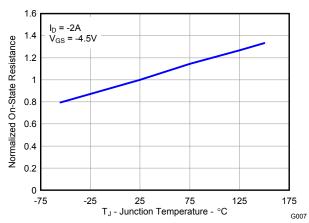
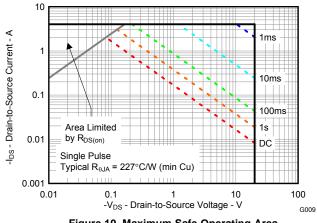
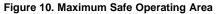


Figure 8. Normalized On-State Resistance vs. Temperature





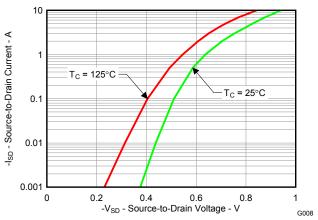


Figure 9. Typical Diode Forward Voltage

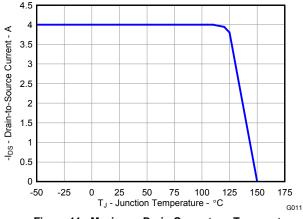


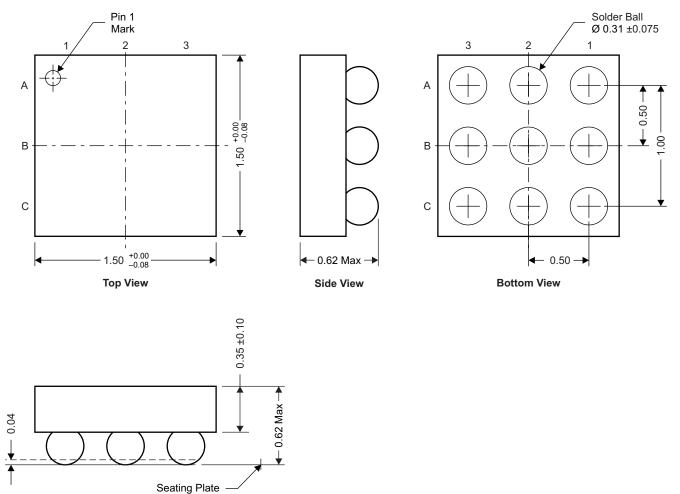
Figure 11. Maximum Drain Current vs. Temperature

TEXAS INSTRUMENTS

www.ti.com

MECHANICAL DATA

CSD25201W15 Package Dimensions



Front View

M0171-01

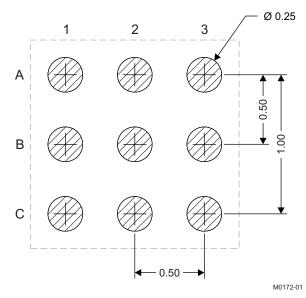
NOTE: All dimensions are in mm (unless otherwise specified)

Pinout

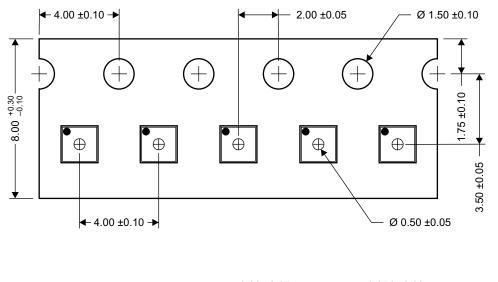
DESIGNATION	
Gate	
Drain	
Source	



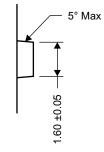
Recommended Land Pattern



NOTE: All dimensions are in mm (unless otherwise specified)



Tape and Reel Information





M0173-01

- NOTES: 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
 - 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
 - 3. Material: black static-dissipative polystyrene
 - 4. All dimensions are in mm (unless otherwise specified)
 - 5. Thickness: 0.30 ±0.05mm
 - 6. MSL1 260°C (IR and convection) PbF reflow compatible

SLPS269A - JUNE 2010-REVISED JULY 2011

REVISION HISTORY

Changes from	Original (June	e 2010) to	Revision A
•	· · · · · · · · · · · · · · · · · ·		

V15

Page

www.ti.com

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Audio	www.ti.com/audio	Communications and Telecom	www.ti.com/communications
Amplifiers	amplifier.ti.com	Computers and Peripherals	www.ti.com/computers
Data Converters	dataconverter.ti.com	Consumer Electronics	www.ti.com/consumer-apps
DLP® Products	www.dlp.com	Energy and Lighting	www.ti.com/energy
DSP	dsp.ti.com	Industrial	www.ti.com/industrial
Clocks and Timers	www.ti.com/clocks	Medical	www.ti.com/medical
Interface	interface.ti.com	Security	www.ti.com/security
Logic	logic.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Power Mgmt	power.ti.com	Transportation and Automotive	www.ti.com/automotive
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com	Wireless	www.ti.com/wireless-apps
RF/IF and ZigBee® Solutions	www.ti.com/lprf		

TI E2E Community Home Page

e2e.ti.com

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2011, Texas Instruments Incorporated